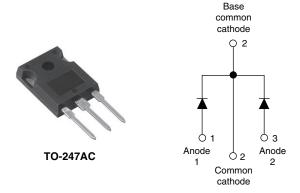


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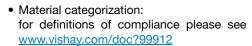
Ultrafast Rectifier, 2 x 40 A FRED Pt®



PRODUCT SUMMARY								
Package	TO-247AC							
I _{F(AV)}	2 x 40 A							
V_{R}	200 V							
V _F at I _F	0.8 V							
t _{rr} typ.	34 ns							
T _J max.	175 °C							
Diode variation	Common cathode							

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47







ROHS
COMPLIANT
HALOGEN
FREE
Available

DESCRIPTIONS / APPLICATIONS

VS-80CPU02... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of welding, SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V_{RRM}		200	V						
Average rectified forward current total device	I _{F(AV)}	T _C = 145 °C	40							
			80	Α						
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C	330							
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-				
Forward voltage		I _F = 40 A	-	0.94	1.02				
	V _F	$I_F = 40 \text{ A}, T_J = 150 ^{\circ}\text{C}$		0.80	0.90	V			
		I _F = 80 A	-	1.07	1.20]			
		I _F = 80 A, T _J = 150 °C	-	0.97	1.08				
Deverage legisers overest	I _R	$V_R = V_R$ rated	-	-	5				
Reverse leakage current		T _J = 150 °C, V _R = V _R rated	-	-	500	μA			
Junction capacitance	C _T	V _R = 200 V	-	120	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH			



VS-80CPU02-F3, VS-80CPU02-N3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS				
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	33	-	ns			
		T _J = 125 °C		-	54	-				
Peak recovery current	I _{RRM}	T _J = 25 °C	$I_F = 40 \text{ A}$	-	3.4	-	Α			
		T _J = 125 °C	dl _F /dt = - 200 A/μs V _R = 200 V	-	8	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C] "	-	56	=	nC			
		T _J = 125 °C		-	216	-	nC nC			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C			
Thermal resistance, junction to case per leg	R _{thJC}		-	0.46	0.70				
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount		-	40	°C/W			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.3	-				
Weight			-	6.0	-	g			
weight			-	0.21	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style TO-247AC	80CPU02						



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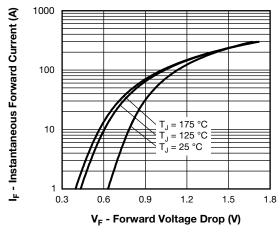


Fig. 1 - Typical Forward Voltage Drop Characteristics

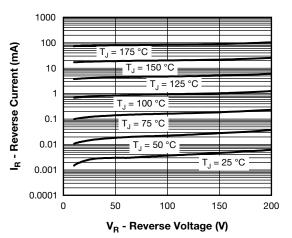


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

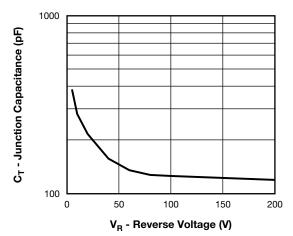


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

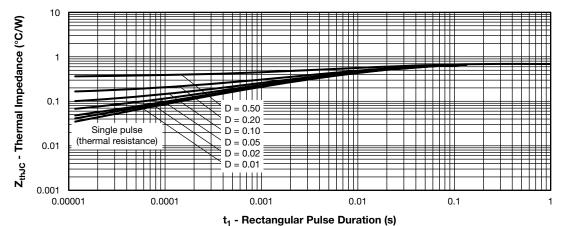


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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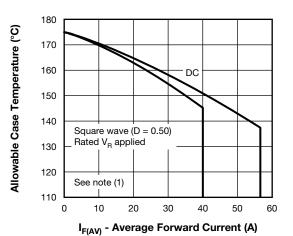


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

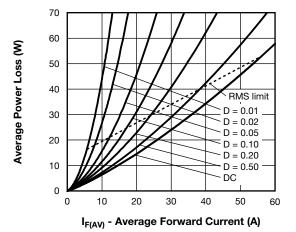


Fig. 6 - Forward Power Loss Characteristics

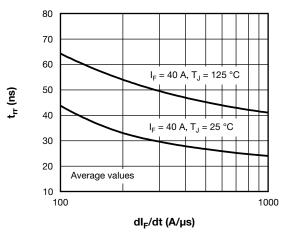


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

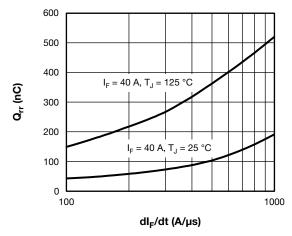


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$

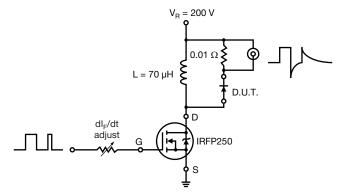
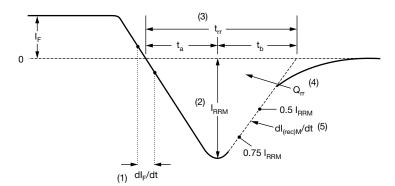


Fig. 9 - Reverse Recovery Parameter Test Circuit

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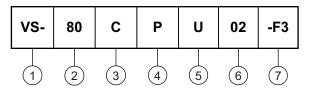


- (1) dl_F/dt rate of change of current through zero crossing
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$
- (2) I_{RRM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going $I_{\rm F}$ to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current.
- (5) $dI_{(rec)M}/dt$ peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (80 = 80 A)
- 3 Circuit configuration:

C = common cathode

- 4 P = TO-247AC
- 5 U = ultrafast rectifier
- 6 Voltage rating (02 = 200 V)
- 7 Environmental digit:
 - -F3 = RoHS-compliant and totally lead (Pb)-free
 - -N3 = halogen-free, RoHS-compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION									
VS-80CPU02-F3	25	500	Antistatic plastic tube						
VS-80CPU02-N3	25	500	Antistatic plastic tube						

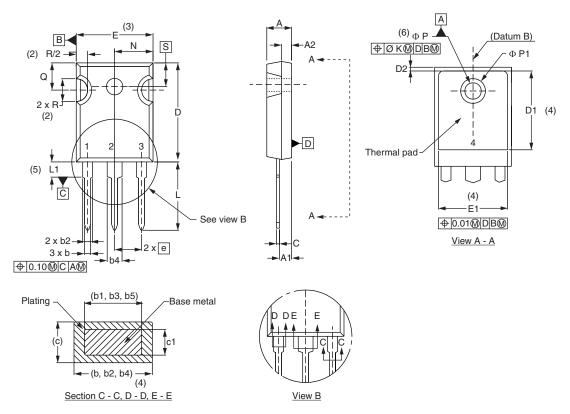
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95542						
Part marking	www.vishay.com/doc?95007						
SPICE model	www.vishay.com/doc?96096						



Vishay Semiconductors

TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



CYMPOL	MILLIMETERS		INCHES		NOTEC	SYMBOL	MILLIMETERS		INCHES		NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØK	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N 7.62 BSC 0.3		7.62 BSC		.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Legal Disclaimer Notice

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